

Specification for Approval

PRODUCT NAME: RGS13128096WH000 PRODUCT NO.: 9914201000

CUSTOMER
APPROVED BY
DATE:

RITDISPLAY CORP. APPROVED	



REVISION RECORD

REV.	REVISION DESCRIPTION	REV. DATE	REMARK
X01	INITIAL RELEASE	2006. 01. 12	
X02	 Add the operating conditions for different luminance Add the panel electrical specification Modify the CIE specification Add the application circuit 	2006. 03. 01	Page 6, 7, 8 & 17
A01	 Modify features Add the information of module weight Modify lifetime specification Modify panel electrical specifications – current, power consumption, luminance & contrast setting 	2006. 05. 08	Page 4, 5, 6, 8 & 20
A02	Correct description of pin assignments	2006. 06. 02	Page 10
A03	 Modify lifetime specification Modify D.C electrical characteristics Modify panel electrical specification – current, power consumption, luminance & contrast setting Modify description of pin assignment Modify 8080-series MPU parallel interface characteristics Modify reliability test conditions Modify seal dimension 	2006. 08. 14	Page 6, 7, 8, 10, 13, 18 & 19
A04	 Modify specification of dark room contrast Modify D.C electrical characteristics Modify CIE tolerance (±0.4→±0.3) Modify power on/off sequence 	2007. 05. 10	Page 4, 7, 8 & 16



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1. SCOPE

The purpose of this specification is to define the general provisions and quality requirements that apply to the supply of display cells manufactured by RiTdisplay. This document, together with the Module Ass'y Drawing, is the highest-level specification for this product. It describes the product, identifies supporting documents and contains specifications.

2. WARRANTY

RiTdisplay warrants that the products delivered pursuant to this specification (or order) will conform to the agreed specifications for twelve (12) months from the shipping date ("Warranty Period"). RiTdisplay is obligated to repair or replace the products which are found to be defective or inconsistent with the specifications during the Warranty Period without charge, on condition that the products are stored or used as the conditions specified in the specifications. Nevertheless, RiTdisplay is not obligated to repair or replace the products without charge if the defects or inconsistency are caused by the force majeure or the reckless behaviors of the customer.

After the Warranty Period, all repairs or replacements of the products are subject to charge.

3. FEATURES

- Small Molecular Passive Organic Light Emission Diode.
- Color: White
- Panel matrix : 128*96Driver IC : SSD1329U2
- Excellent Quick response time: 10µs
- Extremely thin thickness for best mechanism design: 1.65mm.
- High contrast : 2000:1
- Wide viewing angle : 160°
- 8-bit 6800-series Parallel Interface, 8-bit 8080-series Parallel Interface, Serial Peripheral Interface.
- Wide range operating temperature: -40 to 70 °C
- Anti-glare polarizer.



4. MECHANICAL DATA

NO	ITEM	SPECIFICATION	UNIT
1	Dot Matrix	128 (W) x 96 (H)	dot
2	Dot Size	0.19 (W) x 0.19 (H)	mm ²
3	Dot Pitch	0.21 (W) x 0.21 (H)	mm ²
4	Aperture Rate	82	%
5	Active Area	26.86 (W) x 20.14 (H)	mm ²
6	Panel Size	33 (W) x 26.8 (H)	mm ²
7	Panel Thickness	1.65	mm
8	Module Size	33 (W) x 41.6 (H) x 1.65 (T)	mm ³
9	Diagonal A/A size	1.3	inch
10	Module Weight	2.88 ± 10%	gram



5. MAXIMUM RATINGS

ITEM	MIN	MAX	UNIT	Condition	Remark
Supply Voltage (V _{DD})	-0.3	3.5	V	Ta = 25°C	IC maximum rating
Supply Voltage (Vcc)	8	16	V	Ta = 25°C	IC maximum rating
Operating Temp.	-40	70	°C		
Storage Temp	-40	85	°C		
Humidity		85	%		
Life Time	10,000	-	Hrs	120 cd/m², 50% checkerboard	Note (1)
Life Time	13,000	-	Hrs	100 cd/m ² , 50% checkerboard	Note (2)
Life Time	16,000	-	Hrs	80 cd/m², 50% checkerboard	Note (3)

Note:

- (A) Under Vcc = 15V, Ta = 25°C, 50% RH.
- (B) Life time is defined the amount of time when the luminance has decayed to less than 50% of the initial measured luminance.

(1) Setting of 120 cd/m²:

- Contrast setting: 0x95

Frame rate: 85Hz
Duty setting: 1/96
(2) Setting of 100 cd/m²:

- Contrast setting: 0x72

Frame rate: 85HzDuty setting: 1/96

(3) Setting of 80 cd/m²:

- Contrast setting: 0x4F

Frame rate: 85HzDuty setting: 1/96



6. ELECTRICAL CHARACTERISTICS

6.1 D.C ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETERS	TEST CONDITION	MIN	TYP	MAX	UNIT
V _{cc}	Driver power supply (for OLED panel)	Ta=-20°C to +70°C	14.5	15	15.5	V
V_{DD}	Logic operating voltage	Ta=-20°C to +70°C	2.4	2.7	3.5	٧
V_{DDIO}	MCU interface operating voltage	-	1.7	1	V_{DD}	٧
V _{OH}	Hi logic output level	lout=100 uA, 3.3MHz	0.9* V _{DDIO}	-	V_{DDIO}	V
V _{OL}	Low logic output level	lout=100uA, 3.3MHZ	0	ı	0.1* V _{DDIO}	V
V _{IH}	Hi logic input level	lout=100uA, 3.3MHZ	0.8* V _{DDIO}	1	V _{DDIO}	٧
V _{IL}	Low logic input level	lout=100uA, 3.3MHZ	0	ı	0.2* V _{DDIO}	V
I _{CC}	Operating current for V _{CC}	Contrast=80	400	440	480	uA
I _{DD}	Operating current for V _{DD}	Contrast=80	25	40	55	uA
	Segment Output Current Setting:	Contrast=FF	290	320	350	uA
	IREF = 10uA, Display	Contrast=AF	200	220	240	uA
I _{SEG}	ON, Segment pin under test is	Contrast=5F	110	120	130	uA
	connected with a 20K resistive load to VSS.	Contrast=0F	15	20	25	uA

Note : V_{DD} =3.0V ; Frame rate= 85 Hz ; No panel attached.



6.2 ELECTRO-OPTICAL CHARACTERISTICS

PANEL ELECTRICAL SPECIFICATIONS

PARAMETER	MIN	TYP.	MAX	UNITS	COMMENTS
Normal mode current	ı	21	23	mA	All pixels on (1)
Standby mode current	ı	1	3	mA	Standby mode 10% pixels on (2)
Normal mode power consumption	1	315	345	mW	All pixels on (1)
Standby mode power consumption	ı	15	45	mW	Standby mode 10% pixels on (2)
Normal mode Luminance	80	100		cd/m ²	Display Average
Standby mode Luminance		10		cd/m ²	Display Average
CIEx (White)	0.25	0.28	0.31		v v (CIE 1021)
CIEy (White)	0.31	0.34	0.37		x, y (CIE 1931)
Dark Room Contrast	2000:1				
Viewing Angle	160			degree	
Response Time		10		μs	

(1) Normal mode condition:

Driving Voltage : 15VContrast setting : 0x72

Frame rate: 85HzDuty setting: 1/96

(2) Standby mode condition :

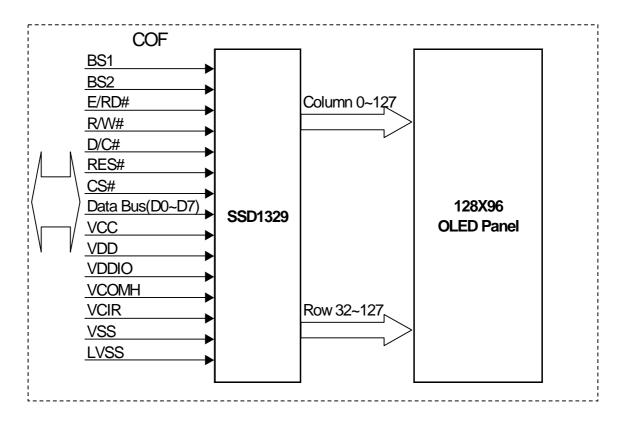
Driving Voltage: 15VContrast setting: 0x00

Frame rate: 85HzDuty setting: 1/96

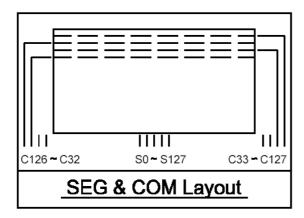


7. INTERFACE

7.1 FUNCTION BLOCK DIAGRAM



7.2 PANEL LAYOUT DIAGRAM



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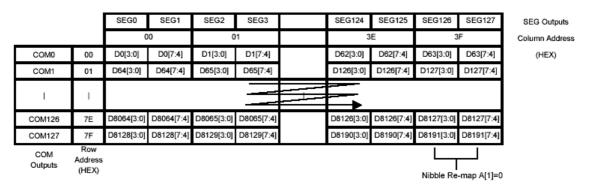
7.3 PIN ASSIGNMENTS

PIN NAME	PIN NO		DESCRIPTION							
NC	1	No co	No connection.							
VCIR	2	No co	nnection and	left float.						
VCOMH	3		/oltage Outp en this pin a		tor shou	ld be connected				
LVSS	4	Groun								
VSS	5	Groun	ıd.							
BS1	6	MCU	parallel interi 6800-parallel interface	face selection 8080-parallel interface	on input. Serial interface					
DOO	7	BS1	0	1	0					
BS2	7	BS2	1	1	0					
IREF	8		Reference current input pin. A resistor should be connected between this pin and V _{DD} .							
CS#	9		select input.							
RES#	10		signal input.		SSD1329	9 is executed.				
D/C#	11	Data/ Pull hi	When it's low, initialization of SSD1329 is executed. Data/ Command control. Pull high for write/read display data. Pull low for write command or read status.							
R/W#	12	MCU	interface inpo	ut.						
Е	13	MCU it's pu	•	ut. Data rea	d operat	ion is initiated when				
D0	14	Data b	ous(for parall	lel interface))					
D1	15	Data b	ous(for parall	lel interface)						
D2	16	_	ous(for parall							
D3	17		ous(for parall							
D4	18		ous(for parall							
D5	19		ous(for parall							
D6	20		ous(for parall	•						
D7	21		ous(for parall							
VDDIO	22		in is a powe		of I/O b	uffer.				
VDD	23	Powe	r supply for lo	ogic.						
VCC	24	Powe	r supply for a	nalog circui	t.					
NC	25	No co	nnection.							

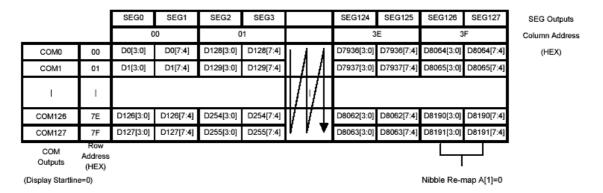


7.4 GRAPHIC DISPLAY DATA RAM ADDRESS MAP

GDDRAM Address Map - Horizontal Address Increment A[2]=0, Column Address Re-map A[0]=0, Nibble Re-map A[1]=0, COM Re-map A[4]=0, Display Start Line=00H (Data byte sequence: D0, D1, D2 ... D8191)



GDDRAM Address Map - Vertical Address Increment A[2]=1, Column Address Re-map A[0]=0, Nibble Re-map A[1]=0, COM Re-map A[4]=0, Display Start Line=00H (Data byte sequence: D0, D1, D2 ... D8191)

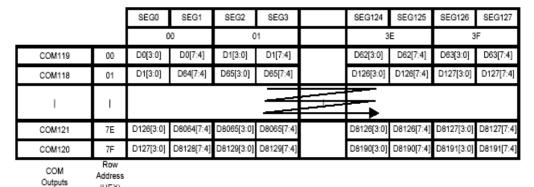


GDDRAM Address Map - Horizontal Address Increment A[2]=0, Column Address Re-map A[0]=1, Nibble Re-map A[1]=1, COM Re-map A[4]=0, Display Start line=00H (Data byte sequence: D0, D1, D2 ... D8191)

											1
		SEG0	SEG1	SEG2	SEG3		SEG124	SEG125	SEG126	SEG127	SEG Outputs
		3	F	3	E		0)1	0	00	Column Address
COM0	00	D63[7:4]	D63[3:0]	D62[7:4]	D62[3:0]		D1[7:4]	D1[3:0]	D0[7:4]	D0[3:0]	(HEX)
COM1	01	D127[7:4]	D127[3:0]	D126[7:4]	D126[3:0]		D65[7:4]	D65[3:0]	D64[7:4]	D64[3:0]	
-	-				111	H					
COM126	7E	D8127[7:4]	D8127[3:0]	D8126[7:4]	D8126[3:0]		D8065[7:4]	D8065[3:0]	D8064[7:4]	D8064[3:0]	
COM127	7F	D8191[7:4]	D8191[3:0]	D8190[7:4]	D8190[3:0]		D8129[7:4]	D8129[3:0]	D8128[7:4]	D8128[3:0]	
COM Outputs	Row Address (HEX)								Nibble Pa	e-map A[1]=	1
(Display Startline=0)									MINDIE IVE	-111ah v[1]-	1

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GDDRAM Address Map - Horizontal Address Increment A[2]=0, Column Address Re-map A[0]=0, Nibble Re-map A[1]=0, COM Re-map A[4]=1, Display Start Line=78H (Data byte sequence: D0, D1, D2 ... D8191)



SEG Outputs Column Address (HEX)

(Display Startline=78H)

(HEX)

GDDRAM Address Map - Horizontal Address Increment A[2]=0, Column Address Re-map A[0]=0, Nibble Re-map A[1]=0, COM Re-map A[4]=0, Display Start Line=00H (Data byte sequence: D0, D1, D2 ... D7811), Column Start Address = 01H, Column End Address = 3EH, Row Start Address = 01H, Row End Address = 7EH

			SEG0	SEG1	SEG2	SEG3		SEG124	SEG125	SEG126	SEG127
			00		0	01		3	E	3	F
Γ	COM0	00									
	COM1	01			D0[3:0]	D0[7:4]		D61[3:0]	D61[7:4]		
	I							l IÎ			
	COM126	7E			D7750[3:0]	D7750[7:4]		D7811[3:0]	D7811[7:4]		
	COM127	7F									
_	0014	Row	•				•				

SEG Outputs Column Address (HEX)

COM Outputs (Display Startline=0)

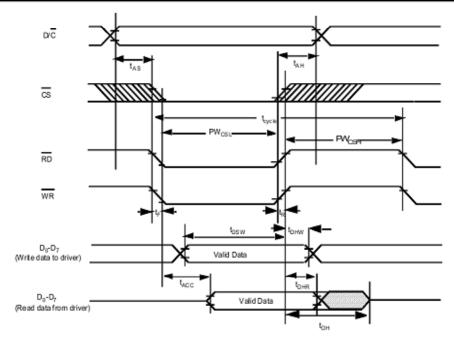
Address



7.5 INTERFACE TIMING CHART

8080-Series MPU Parallel Interface Timing Characteristics (V_{DD} - V_{SS} = 2.4 to 3.5V, T_A = -30 to 85°C)

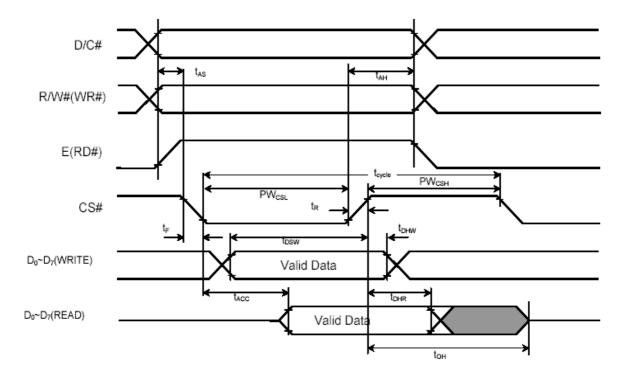
Symbol	Parameter	Min	Тур	Max	Unit
t _{cycle}	Clock Cycle Time	300	-	-	ns
t _{AS}	Address Setup Time	0		-	ns
t _{AH}	Address Hold Time	0	-	-	ns
tosw	Write Data Setup Time	40	-	-	ns
t _{DHW}	Write Data Hold Time	15	-	-	ns
t _{DHR}	Read Data Hold Time	20	-	-	ns
t _{он}	Output Disable Time	-	-	70	ns
tacc	Access Time	-		140	ns
PW _{CSL}	Chip Select Low Pulse Width (read) Chip Select Low Pulse Width (write)	120 60		-	ns
PW _{CSH}	Chip Select High Pulse Width (read) Chip Select High Pulse Width (write)	60 60	-	-	ns
t _R	Rise Time	-	-	15	ns
t _F	Fall Time	-	-	15	ns



8080-series MPU Parallel Interface Characteristics

6800-Series MPU Parallel Interface Timing Characteristics (VDD - Vss = 2.4 to 3.5V, TA = 25°C)

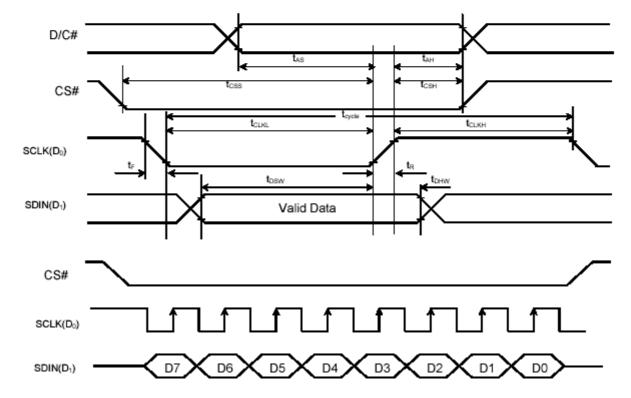
Symbol	Parameter	Min	Тур	Max	Unit
t _{cycle}	Clock Cycle Time	300	-	-	ns
t _{AS}	Address Setup Time	0	-	-	ns
t _{ah}	Address Hold Time	0	-	-	ns
t _{DSW}	Write Data Setup Time	40	-	-	ns
t _{DHW}	Write Data Hold Time	15	-	-	ns
t _{DHR}	Read Data Hold Time	20	-	-	ns
t _{он}	Output Disable Time	-	-	70	ns
t _{ACC}	Access Time	-	-	140	ns
PWcsL	Chip Select Low Pulse Width (read) Chip Select Low Pulse Width (write)	120 60	-	-	ns
PW _{CSH}	Chip Select High Pulse Width (read) Chip Select High Pulse Width (write)	60 60	-	-	ns
t _R	Rise Time	-	-	15	ns
t _F	Fall Time	-	-	15	ns



6800-series MPU Parallel Interface Characteristics

Serial Interface Timing Characteristics (VDD- Vss = 2.4 to 3.5V, TA = 25°C)

Symbol	Parameter	Min	Тур	Max	Unit
t _{cycle}	Clock Cycle Time	250	,	,	ns
t _{AS}	Address Setup Time	150	,	,	ns
t _{AH}	Address Hold Time	150	,	,	ns
t _{css}	Chip Select Setup Time	120			ns
t _{сsн}	Chip Select Hold Time	60	,	,	ns
t _{DSW}	Write Data Setup Time	100	,		ns
t _{DHW}	Write Data Hold Time	100	,	,	ns
t _{CLKL}	Clock Low Time	100	-		ns
t _{CLKH}	Clock High Time	100	,	,	ns
t _R	Rise Time	-	,	15	ns
t _F	Fall Time	-	'	15	ns



Serial Interface Characteristics

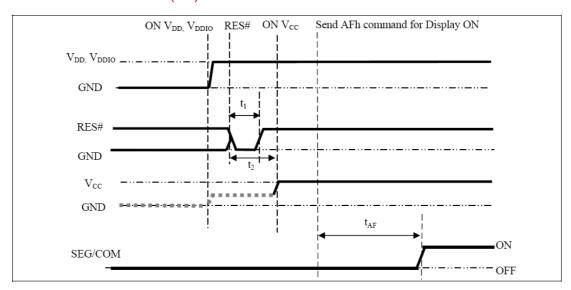


8. POWER ON / OFF SEQUENCE & APPLICATION CIRCUIT

8.1 POWER ON / OFF SEQUENCE

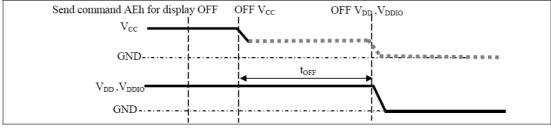
Power ON sequence:

- 1. Power ON VDD, VDDIO.
- 2. After VDD, VDDIO become stable, set RES# pin LOW (logic low) for at least 3us(t1) and then HIGH (logic high).
- 3. After set RES# pin LOW (logic low), wait for at least 3us(t2). Then Power ON Vcc.(1)
- 4. After Vcc become stable, send command AFh for display ON. SEG/COM will be ON after 100ms(tAF).



Power OFF sequence:

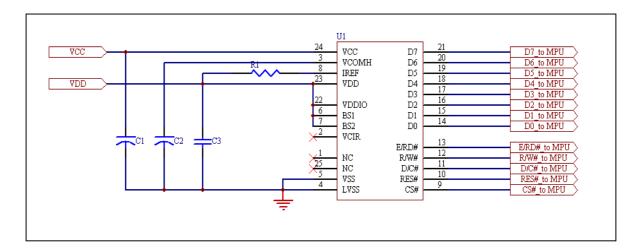
- 1. Send command AEh for display OFF.
- 2. Power OFF Vcc. (1), (2)
- 3. Wait for toff. Power OFF VDD, VDDIO. (where Minimum toff=0ms, Typical toff=100ms)



Note:

- (1) Since an ESD protection circuit is connected between VDD, VDDIO and VCC, VCC becomes lower than VDD whenever VDD, VDDIO is ON and VCC is OFF as shown in the dotted line of VCC in above figures.
- (2) Vcc should be disabled when it is OFF.

8.2 APPLICATION CIRCUIT



U1: 128x96 OLED module C1: 4.7uF, tantalum type C2: 1uF, tantalum type

C3: 0.1uF

R1: 200 K ohm, tolerance 1%

8.3 COMMAND TABLE

Refer to IC Spec.: SSD1329



9. RELIABILITY TEST CONDITIONS

No.	Items	Specification	Quantity
1	High temp. (Non-operation)	85°C, 240hrs	5
2	High temp. (Operation)	70°C, 120hrs	5
3	Low temp. (Operation)	-40°C, 120hrs	5
4	High temp. / High humidity (Operation)	65°C, 90%RH, 120hrs	5
5	Thermal shock (Non-operation)	-40°C ~85°C (-40°C /30min; transit /3min; 85°C /30min; transit /3min) 1cycle: 66min, 100 cycles	5
6	Vibration	Frequency: 5~50HZ, 0.5G Scan rate: 1 oct/min Time: 2 hrs/axis Test axis: X, Y, Z	1 Carton
7	Drop	Height: 120cm Sequence : 1 angle \ 3 edges and 6 faces Cycles: 1	1 Carton
8	ESD (Non-operation)	Air discharge model, ±8kV, 10 times	5

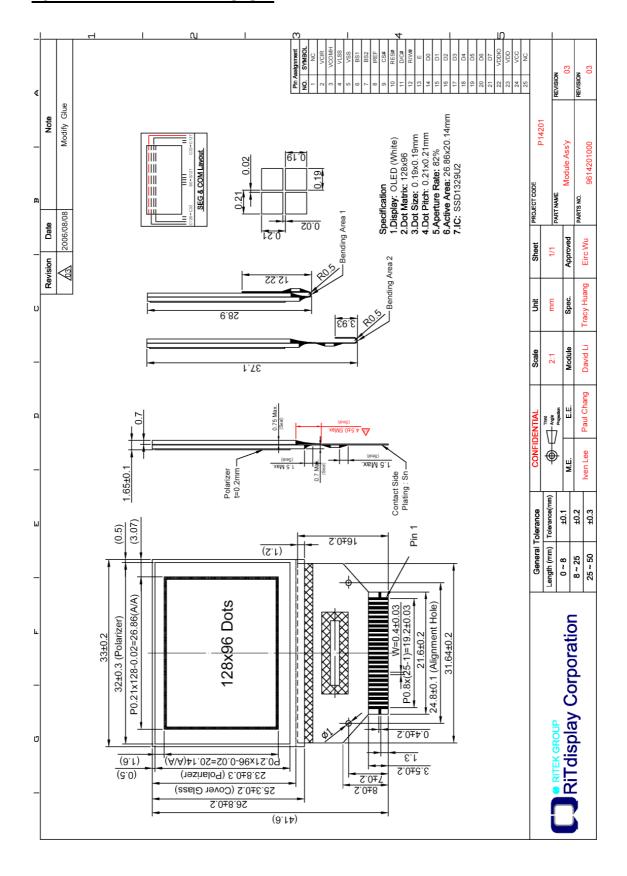
Test and measurement conditions

- 1. All measurements shall not be started until the specimens attain to temperature stability.
- 2. All-pixels-on is used as operation test pattern.
- 3. The degradation of Polarizer are ignored for item 1, 4 & 5.

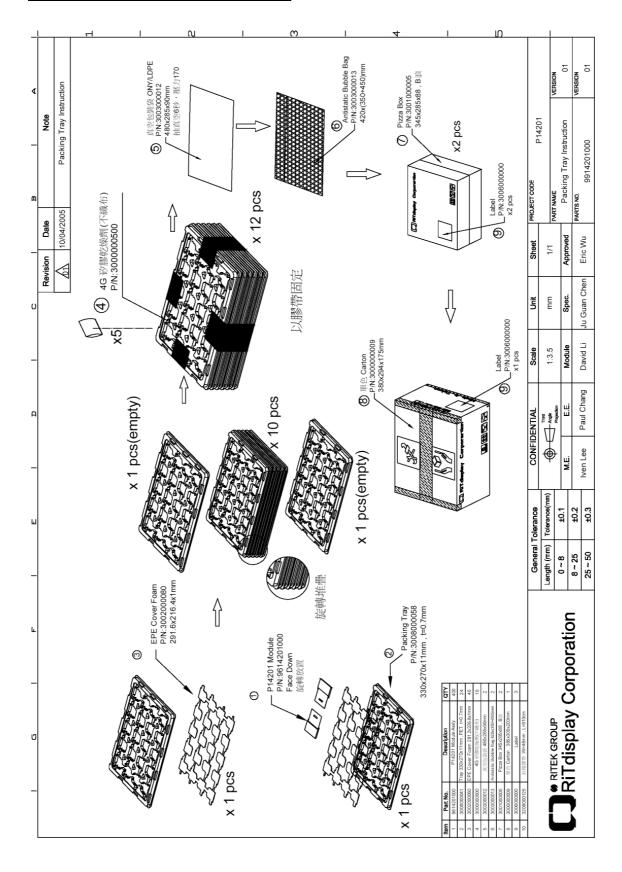
Evaluation criteria

- 1. The function test is OK.
- 2. No observable defects.
- 3. Luminance: > 50% of initial value.
- 4. Current consumption: within \pm 50% of initial value.

10. EXTERNAL DIMENSION



11. PACKING SPECIFICATION



12. APPENDIXES

APPENDIX 1: DEFINITIONS

A. DEFINITION OF CHROMATICITY COORDINATE

The chromaticity coordinate is defined as the coordinate value on the CIE 1931 color chart for R, G, B, W.

B. DEFINITION OF CONTRAST RATIO

The contrast ratio is defined as the following formula:

C. DEFINITION OF RESPONSE TIME

The definition of turn-on response time Tr is the time interval between a pixel reaching 10% of steady state luminance and 90% of steady state luminance. The definition of turn-off response time Tf is the time interval between a pixel reaching 90% of steady state luminance and 10% of steady state luminance. It is shown in Figure 2.

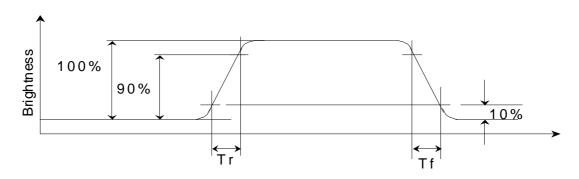


Figure 2 Response time

D. DEFINITION OF VIEWING ANGLE

The viewing angle is defined as Figure 3. Horizontal and vertical (H & V) angles are determined for viewing directions where luminance varies by 50% of the perpendicular value.

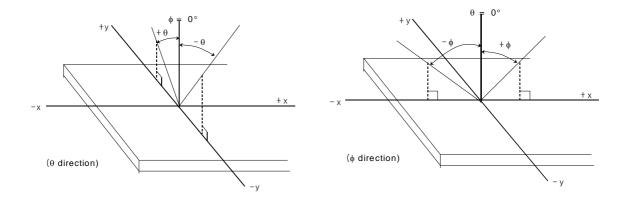
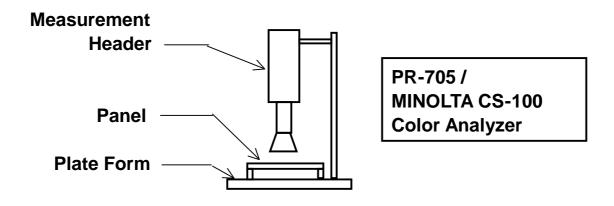


Figure 3 Viewing angle

APPENDIX 2: MEASUREMENT APPARATUS

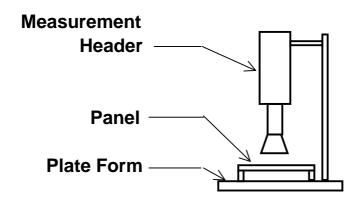
A. LUMINANCE/COLOR COORDINATE

PHOTO RESEARCH PR-705, MINOLTA CS-100



B. CONTRAST / RESPONSE TIME / VIEW ANGLE

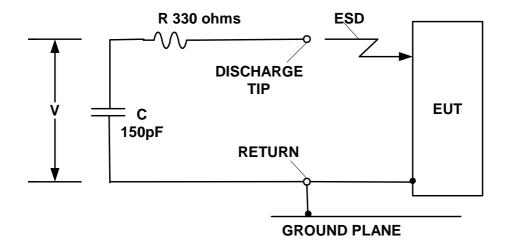
WESTAR CORPORATION FPM-510



Westar FPM-510
Display Contrast /
Response time /
View angle Analyzer



C. ESD ON AIR DISCHARGE MODE





APPENDIX 3: PRECAUTIONS

A. RESIDUE IMAGE

Because the pixels are lighted in different time, the luminance of active pixels may reduce or differ from inactive pixels. Therefore, the residue image will occur. To avoid the residue image, every pixel needs to be lighted up uniformly.